

LM748 Operational Amplifier

General Description

The LM748 is a general purpose operational amplifier with external frequency compensation.

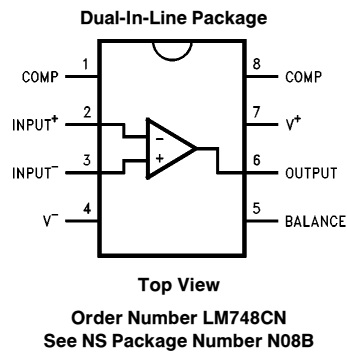
The unity-gain compensation specified makes the circuit stable for all feedback configurations, even with capacitive loads. It is possible to optimize compensation for best high frequency performance at any gain. As a comparator, the output can be clamped at any desired level to make it compatible with logic circuits.

The LM748C is specified for operation over the 0°C to +70°C temperature range.

Features

- Frequency compensation with a single 30 pF capacitor
- Operation from $\pm 5\text{V}$ to $\pm 20\text{V}$
- Continuous short-circuit protection
- Operation as a comparator with differential inputs as high as $\pm 30\text{V}$
- No latch-up when common mode range is exceeded
- Same pin configuration as the LM101

Connection Diagram



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Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	±22V
Power Dissipation (Note 1)	500 mW
Differential Input Voltage	±30V

Input Voltage (Note 2)	±15V
Output Short-Circuit Duration (Note 3)	
Operating Temperature Range: LM748C	0°C to +70°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	+300°C

Electrical Characteristics (Note 4)

Parameter	Conditions	Min	Typ	Max	Units
Input Offset Voltage	$T_A = 25^\circ\text{C}$, $R_S \leq 10\text{ k}\Omega$		1.0	5.0	mV
Input Offset Current	$T_A = 25^\circ\text{C}$		40	200	nA
Input Bias Current	$T_A = 25^\circ\text{C}$		120	500	nA
Input Resistance	$T_A = 25^\circ\text{C}$	300	800		k Ω
Supply Current	$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$		1.8	2.8	mA
Large Signal Voltage Gain	$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$ $V_{OUT} = \pm 10\text{V}$, $R_L \geq 2\text{ k}\Omega$	50	160		V/mV
Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$			6.0	mV
Average Temperature Coefficient of Input Offset Voltage	$R_S \leq 50\Omega$		3.0		$\mu\text{V}/^\circ\text{C}$
	$R_S \leq 10\text{ k}\Omega$		6.0		$\mu\text{V}/^\circ\text{C}$
Input Offset Current	$T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$			300	nA
	$T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$			500	nA
Input Bias Current	$T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$			0.8	μA
	$T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$			1.5	μA
Supply Current	$T_A = +125^\circ\text{C}$, $V_S = \pm 15\text{V}$		1.2	2.25	mA
	$T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$		1.9	3.3	mA
Large Signal Voltage Gain	$V_S = \pm 15\text{V}$, $V_{OUT} = \pm 10\text{V}$ $R_L \geq 2\text{ k}\Omega$	25			V/mV
Output Voltage Swing	$V_S = \pm 15\text{V}$, $R_L = 10\text{ k}\Omega$	±12	±14		V
	$V_S = \pm 15\text{V}$, $R_L = 2\text{ k}\Omega$	±10	±13		V
Input Voltage Range	$V_S = \pm 15\text{V}$	±12			V
Common-Mode Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	77	90		dB

Note 1: For operating at elevated temperatures, the device must be derated based on a maximum junction to case thermal resistance of 45°C per watt, or 150°C per watt junction to ambient. (See Curves).

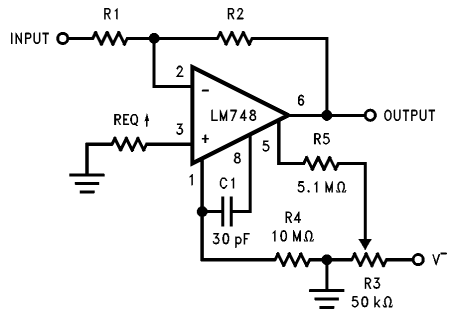
Note 2: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Continuous short circuit is allowed for case temperatures to +125°C and ambient temperatures to +70°C.

Note 4: These specifications apply for $\pm 5\text{V} \leq V_S \leq +15\text{V}$ and $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$, unless otherwise specified.

Typical Applications

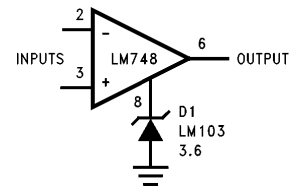
Inverting Amplifier with Balancing Circuit



†May be zero or equal to parallel combination of R1 and R2 for minimum offset.

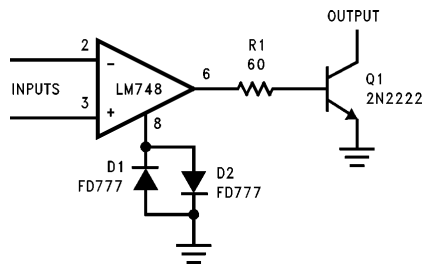
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Voltage Comparator for Driving DTL or TTL Integrated Circuits



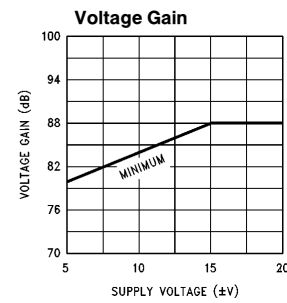
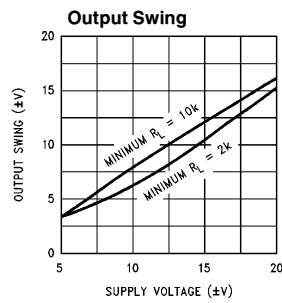
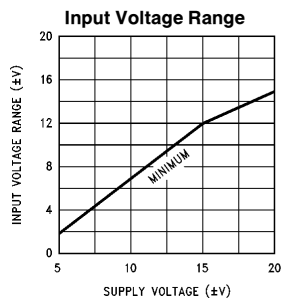
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Voltage Comparator for Driving RTL Logic or High Current Driver



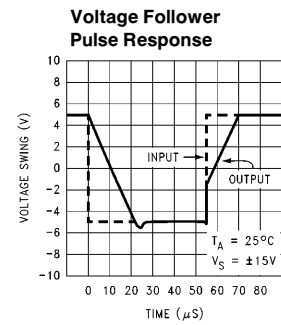
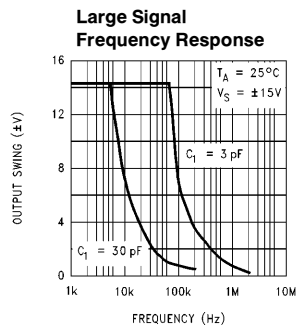
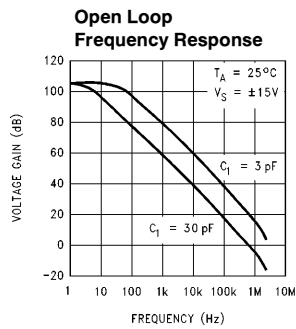
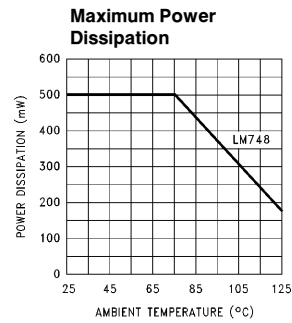
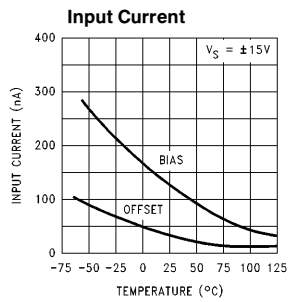
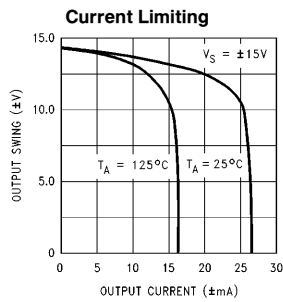
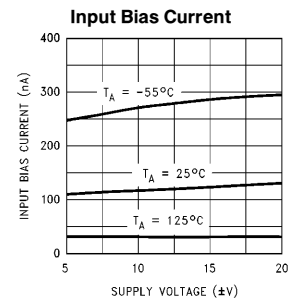
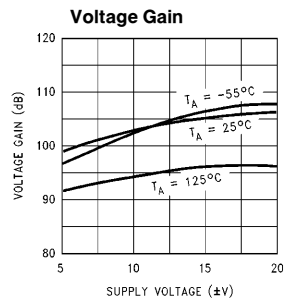
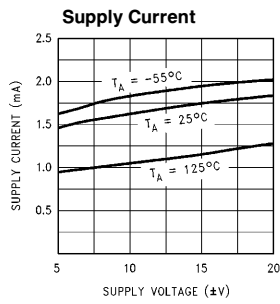
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Guaranteed Performance Characteristics (Note 4)



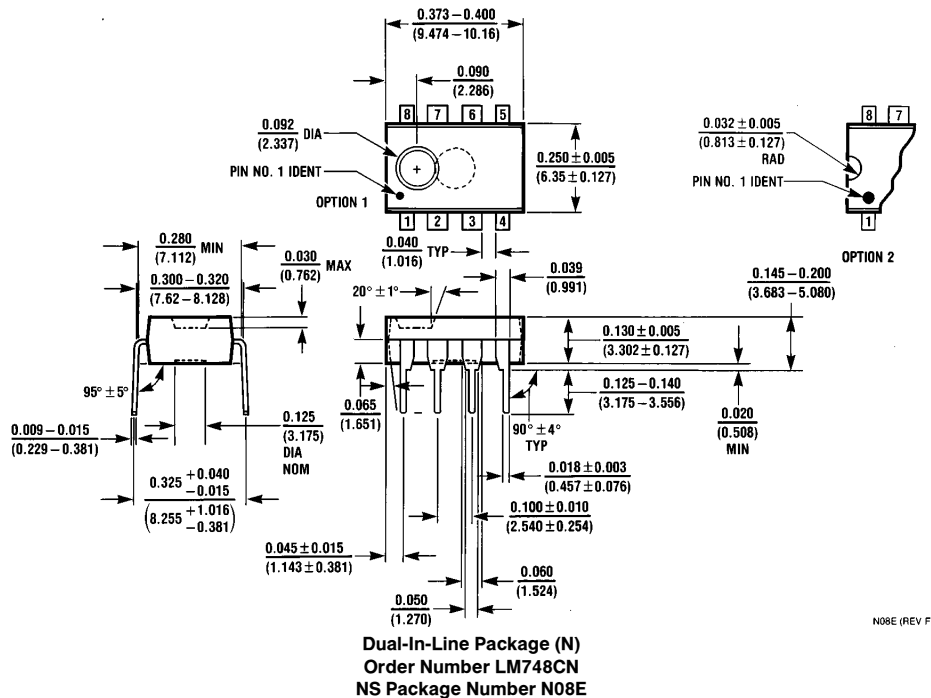
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Typical Performance Characteristics



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Physical Dimensions inches (millimeters)**LIFE SUPPORT POLICY**

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National Semiconductor Corporation
 1111 West Bardin Road
 Arlington, TX 76017
 Tel: (800) 272-9959
 Fax: (800) 737-7018

National Semiconductor Europe
 Fax: (+49) 0-180-530 85 86
 Email: cnjwge@tevm2.nsc.com
 Deutsch Tel: (+49) 0-180-530 85 85
 English Tel: (+49) 0-180-532 78 32
 Français Tel: (+49) 0-180-532 93 58
 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
 19th Floor, Straight Block,
 Ocean Centre, 5 Canton Rd.
 Tsimshatsui, Kowloon
 Hong Kong
 Tel: (852) 2737-1600
 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
 Tel: 81-043-299-2309
 Fax: 81-043-299-2408

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